


7. The semiconductor laser device according to claim 3,
wherein the coefficient of light confinement to the active layer
ranges from 1% to 2%.

8. The semiconductor laser device according to claim 4,
wherein the coefficient of light confinement to the active layer
ranges from 1% to 2%.

REMARKS

The present amendment removes all multiple dependent claims
without changing the scope of coverage.

Respectfully submitted,


HERBERT GOODMAN
Reg. No. 17,081

Frishauf, Holtz, Goodman,
Langer & Chick, P.C.
767 Third Ave., 25th floor
New York, NY 10017-2023
Telephone: (212) 319-4900
Facsimile: (212) 319-5101

HG/lpv